

Hall ICs Hall ICs

PEPEre RoHM Electronic Components

BU52002GUL,BU52003GUL,BU52012NVX,BU52012HFV,BU52013HFV

No.10045ECT03

Description

The unipolar Detection Hall IC detects only either the N pole or S pole. The output turns ON (active Low) upon detection.

Features

- 1) Unipolar detection
- 2) Micropower operation (small current using intermittent operation method)
- 3) Ultra-compact CSP4 package (BU52002GUL, BU52003GUL)
- 4) Ultra- Small outline package (BU52012NVX)
- 5) Small outline package (BU52012HFV, BU52013HFV)
- Line up of supply voltage For 1.8V Power supply voltage (BU52012NVX, BU52012HFV, BU52013HFV) For 3.0V Power supply voltage (BU52002GUL, BU52003GUL)
- 7) High ESD resistance 8kV(HBM)

Applications

Mobile phones, notebook computers, digital video camera, digital still camera, etc.

●Lineup matrix

Function	Product name	Supply voltage (V)	Operate point (mT)	Hysteresis (mT)	Period (ms)	Supply current (AVG.) (µA)	Output type	Package
	BU52002GUL	2.40~3.30	3.7 *	0.8	50	6.5	CMOS	VCSP50L1
S pole	BU52012NVX	1.65~3.60	3.0 *	0.9	50	3.5	COMS	SSON004X1216
	BU52012HFV	1.65~3.30	3.0 *	0.9	50	3.5	CMOS	HVSOF5
	BU52003GUL	2.40~3.30	-3.7 *	0.8	50	6.5	CMOS	VCSP50L1
N pole	BU52013HFV	1.65~3.30	-3.0 *	0.9	50	3.5	CMOS	HVSOF5

 $\ensuremath{\ensuremath{\mathbb{K}}}\xspace{\ensuremath{\mathsf{Plus}}\xspace}$ is expressed on the S-pole; minus on the N-pole

BU52012NVX (Ta=25°C) Parameter

Power Supply Voltage

Output Current

Operating

Storage

Power Dissipation

Temperature Range

Temperature Range %3. Not to exceed Pd Symbol

 V_{DD}

IOUT

Pd

Topr

T_{stg}

%4. Reduced by 5.36mW for each increase in Ta of 1°C over 25°C (mounted on 70mm × 70mm × 1.6mm Glass-epoxy PCB)

Unit

V

mΑ

mW

°C

°C

Ratings

-0.1~+4.5^{**3}

 ± 0.5

2049 **4

-40~+85

-40~+125

Absolute maximum ratings

BU52002GUL,BU52003GUL (Ta=25°C)

Symbol	Ratings	Unit				
V_{DD}	-0.1 ~ +4.5 ^{%1}	V				
I _{OUT}	±1	mA				
Pd	420 ^{**2}	mW				
T _{opr}	-40~+85	°C				
T _{stg}	-40~+125	°C				
	V _{DD} I _{OUT} Pd T _{opr}	V _{DD} -0.1~+4.5 ^{×1} I _{OUT} ±1 Pd 420 ^{×2} T _{opr} -40~+85				

%1. Not to exceed Pd

%2. Reduced by 4.20mW for each increase in Ta of 1°C over 25°C (mounted on 50mm × 58mm Glass-epoxy PCB)

BU52012HFV,BU52013HFV (Ta=25°C)

		, 	
Parameter	Symbol	Ratings	Unit
Power Supply Voltage	V _{DD}	-0.1~+4.5 ^{**5}	V
Output Current	I _{OUT}	±0.5	mA
Power Dissipation	Pd	536 ^{%6}	mW
Operating Temperature Range	T _{opr}	-40~+85	°C
Storage Temperature Range	T _{stg}	-40~+125	°C

※5. Not to exceed Pd

%6. Reduced by 5.36mW for each increase in Ta of 1°C over 25°C (mounted on 70mm × 70mm × 1.6mm Glass-epoxy PCB)

Magnetic, Electrical characteristics

BU52002GUL (Unless otherwise specified, V_{DD}=3.0V, Ta=25°C)

Parameter	Symbol	Limits			Unit	Conditions	
Farameter	Symbol	Min. Ty	Тур.	Max.	Unit	Conditions	
Power Supply Voltage	V_{DD}	2.4	3.0	3.3	V		
Operate Point	BopS	-	3.7	5.5	mT		
Release Point	B _{rpS}	0.8	2.9	-	mT		
Hysteresis	B _{hysS}	-	0.8	-	mT		
Period	T _P	-	50	100	ms		
Output High Voltage	V _{OH}	V _{DD} -0.4	-	-	V	B <b<sub>rpS ^{%7} I_{OUT}=-1.0mA</b<sub>	
Output Low Voltage	V _{OL}	-	-	0.4	V	B _{opS} <b *<sup="">7 I_{OUT} =+1.0mA	
Supply Current	I _{DD(AVG)}	-	6.5	9	μA	Average	
Supply Current During Startup Time	I _{DD(EN)}	-	4.7	-	mA	During Startup Time Value	
Supply Current During Standby Time	I _{DD(DIS)}	-	3.8	-	μA	During Standby Time Value	

%7. B = Magnetic flux density

1mT=10Gauss

Positive ("+") polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor. After applying power supply, it takes one cycle of period (T_P) to become definite output.

Radiation hardiness is not designed.

BU52003GUL (Unless otherwise specified, V _{DD} =3.0V, Ta=25 C)						
Parameter	Symbol	Limits		Unit	Conditions	
	- ,	Min.	Тур.	Max.		
Power Supply Voltage	V_{DD}	2.4	3.0	3.3	V	
Operate Point	B _{opN}	-5.5	-3.7	-	mT	
Release Point	B _{rpN}	-	-2.9	-0.8	mT	
Hysteresis	B_{hysN}	-	0.8	-	mT	
Period	Τ _Ρ	-	50	100	ms	
Output High Voltage	V _{OH}	V _{DD} -0.4	-	-	V	B _{rpN} <b <sup="">%8 I_{OUT}=-1.0mA
Output Low Voltage	V _{OL}	-	-	0.4	V	B <b<sub>opN ^{%8} I_{OUT} =+1.0mA</b<sub>
Supply Current	I _{DD(AVG)}	-	6.5	9	μA	Average
Supply Current During Startup Time	I _{DD(EN)}	-	4.7	-	mA	During Startup Time Value
Supply Current During Standby Time	I _{DD(DIS)}	-	3.8	-	μA	During Standby Time Value

BU52003GUL (Unless otherwise specified, V_DD=3.0V, Ta=25°C)

%8. B = Magnetic flux density

1mT=10Gauss

Parameter Symbol		Limits			Unit	Conditions
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Power Supply Voltage	V_{DD}	1.65	1.80	3.60	V	
Operate Point	B _{opS}	-	3.0	5.0	mT	
Release Point	B _{rpS}	0.6	2.1	-	mT	
Hysteresis	B _{hysS}	-	0.9	-	mT	
Period	T _P	-	50	100	ms	
Output High Voltage	V _{OH}	V _{DD} -0.2	-	-	V	B <b<sub>rpS ^{%9} I_{OUT} =-0.5mA</b<sub>
Output Low Voltage	V _{OL}	-	-	0.2	V	B _{opS} <b *<sup="">9 I_{OUT} =+0.5mA
Supply Current 1	I _{DD1(AVG)}	-	3.5	5.5	μA	V _{DD} =1.8V, Average
Supply Current During Startup Time 1	I _{DD1(EN)}	-	2.8	-	mA	V _{DD} =1.8V, During Startup Time Value
Supply Current During Standby Time 1	I _{DD1(DIS)}	-	1.8	-	μA	V _{DD} =1.8V, During Standby Time Value
Supply Current 2	I _{DD2(AVG)}	-	8.0	12.5	μA	V _{DD} =3.0V, Average
Supply Current During Startup Time 2	I _{DD2(EN)}	-	5.3	-	mA	V _{DD} =3.0V, During Startup Time Value
Supply Current During Standby Time 2	I _{DD2(DIS)}	-	5.2	-	μA	V _{DD} =3.0V, During Standby Time Value

BU52012NVX (Unless otherwise specified, V_{DD}=1.80V, Ta=25°C)

%9. B = Magnetic flux density

1mT=10Gauss

Parameter Symbol		Limits			Unit	Conditions
Falametei	Symbol	Min.	Тур.	Max.	Unit	Conditions
Power Supply Voltage	V_{DD}	1.65	1.80	3.30	V	
Operate Point	B_{opS}	-	3.0	5.0	mT	
Release Point	B _{rpS}	0.6	2.1	-	mT	
Hysteresis	B _{hysS}	-	0.9	-	mT	
Period	Τ _Ρ	-	50	100	ms	
Output High Voltage	V _{OH}	V _{DD} -0.2	-	-	V	B <b<sub>rpS *¹⁰ I_{OUT} =-0.5mA</b<sub>
Output Low Voltage	V _{OL}	-	-	0.2	V	B _{opS} <b ×10<br="">I_{OUT} =+0.5mA
Supply Current 1	I _{DD1(AVG)}	-	3.5	5.5	μA	V _{DD} =1.8V, Average
Supply Current During Startup Time 1	I _{DD1(EN)}	-	2.8	-	mA	V _{DD} =1.8V, During Startup Time Value
Supply Current During Standby Time 1	I _{DD1(DIS)}	-	1.8	-	μA	V _{DD} =1.8V, During Standby Time Value
Supply Current 2	I _{DD2(AVG)}	-	6.5	9	μA	V _{DD} =2.7V, Average
Supply Current During Startup Time 2	I _{DD2(EN)}	-	4.5	-	mA	V _{DD} =2.7V, During Startup Time Value
Supply Current During Standby Time 2	I _{DD2(DIS)}	-	4.0	-	μA	V _{DD} =2.7V, During Standby Time Value

BU52012HFV (Unless otherwise specified, V_{DD}=1.80V, Ta=25°C)

%10. B = Magnetic flux density

1mT=10Gauss

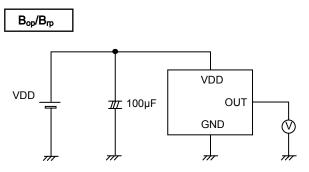
Parameter	Symbol	Limits		Unit	Conditions	
Farameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Power Supply Voltage	V_{DD}	1.65	1.80	3.30	V	
Operate Point	B _{opN}	-5.0	-3.0	-	mT	
Release Point	B _{rpN}	-	-2.1	-0.6	mT	
Hysteresis	B _{hysN}	-	0.9	-	mT	
Period	T _P	-	50	100	ms	
Output High Voltage	V _{OH}	V _{DD} -0.2	-	-	V	B _{rpN} <b *<sup="">11 I_{OUT} =-0.5mA
Output Low Voltage	V _{OL}	-	-	0.2	V	B <b<sub>opN **¹¹ I_{OUT} =+0.5mA</b<sub>
Supply Current 1	I _{DD1(AVG)}	-	3.5	5.5	μA	V _{DD} =1.8V, Average
Supply Current During Startup Time 1	I _{DD1(EN)}	-	2.8	-	mA	V _{DD} =1.8V, During Startup Time Value
Supply Current During Standby Time 1	I _{DD1(DIS)}	-	1.8	-	μA	V _{DD} =1.8V, During Standby Time Value
Supply Current 2	I _{DD2(AVG)}	-	6.5	9	μA	V _{DD} =2.7V, Average
Supply Current During Startup Time 2	I _{DD2(EN)}	-	4.5	-	mA	V _{DD} =2.7V, During Startup Time Value
Supply Current During Standby Time 2	I _{DD2(DIS)}	-	4.0	-	μA	V _{DD} =2.7V, During Standby Time Value

BU52013HFV (Unless otherwise specified, V_{DD}=1.80V, Ta=25°C)

%11. B = Magnetic flux density

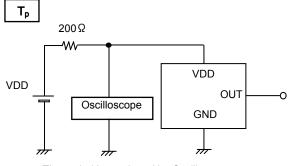
1mT=10Gauss

•Figure of measurement circuit



Bop and Brp are measured with applying the magnetic field from the outside.

Fig.1 Bop, Brp measurement circuit



The period is monitored by Oscilloscope.

Fig.2 T_p measurement circuit

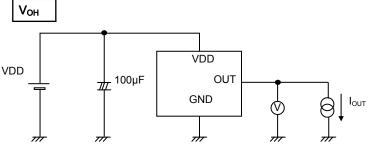
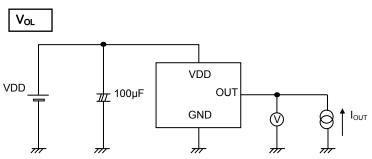


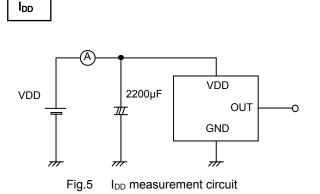
Fig.3 V_{OH} measurement circuit

Product Name	I _{OUT}
BU52002GUL, BU52003GUL	1.0mA
BU52012NVX, BU52012HFV, BU52013HFV	0.5mA



Product Name	I _{OUT}
BU52002GUL, BU52003GUL	1.0mA
BU52012NVX, BU52012HFV, BU52013HFV	0.5mA

Fig.4 V_{OL} measurement circuit



Technical (Reference) Data BU52002GUL (VDD=2.4~3.3V type) 80 8.0 100 MAGNETIC FLUX DENSITY [mT] Ta = 25°C MAGNETIC FLUX DENSITY [mT] 3 O 90 =3.DV 6.0 6.0 Bop S Bop S 80 4.0 4.0 70 2.0 2.0 PERIOD [ms] Brp S 60 Brp S 0.0 0.0 50 -2.0 40 -2.0 30 -4.0 -4.0 20 -6.0 -6.0 10 -8.0 -8.0 0 -60 -40 -20 0 20 40 60 80 100 -40 -20 0 20 40 60 80 AMBIENT TEMPERATURE [°C] 2.0 2.4 2.8 3.2 3.6 -60 100 SUPPLY VOLTAGE [V] AMBIENT TEMPERATURE [°C] Fig.6 Bop,Brp - Ambient temperature Bop,Brp - Supply voltage T_P –Ambient temperature Fig.7 Fig.8 Y 20.0 100 20.0 90 Ta = 25°C AVERAGE SUPPLY CURRENT Ta = 25°C 16.0 80 14.0 70 [ms] 12.0 60 10.0 50 PERIOD 8.0 40 60 30 20 4.0 2.0 10 0.0 0 -60 -40 -20 0 20 40 60 80 100 2.8 3.2 3.6 2.0 2.4 2.8 3.2 3.6 2.4 2.0 SUPPLY VOLTAGE [V] SUPPLY VOLTAGE [V] AMBIENT TEMPERATURE [°C] Fig.11 I_{DD} – Supply voltage Fig.10 I_{DD} – Ambient temperature Fig.9 T_P – Supply voltage BU52003GUL (VDD=2.4~3.3V type) 8.0 8.0 100 MAGNETIC FLUX DENSITY [mT] MAGNETIC FLUX DENSITY [mT] 90 6.0 $Ta = 25^{\circ}C$ 6.0 DD=3.0 _{'DD}=3.0 80 4.0 4.0 70 2.0 2.0 PERIOD [ms] 60 0.0 0.0 50 40 Brp N Brp N -2.0 -2.0 30 -4.0 -4.0 20 Bop N Bop N -6.0 -6.0 10 -80 -80 0 -60 -40 -20 0 20 40 60 80 100 -40 -20 0 20 40 60 80 100 AMBIENT TEMPERATURE [°C] -60 20 24 28 32 36 SUPPLY VOLTAGE [V] AMBIENT TEMPERATURE [°C] Fig.14 T_P – Ambient temperature Fig.13 Bop,Brp – Supply voltage Fig.12 Bop,Brp – Ambient temperature 100 20.0 20.0 AVERAGE SUPPLY CURRENT [µA] AVERAGE SUPPLY CURRENT [µA] 90 Ta = 25°C 18.0 18.0 Ta = 25' 80 16.0 16.0 14.0 70 14.0 <u></u>60 12.0 12.0

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2.8

SUPPLY VOLTAGE [V]

Fig.15 T_P –Supply voltage

3.2

3.6

30

20

10

0

2.0

2.4

-60 -40 -20 0 20 40 60

AMBIENT TEMPERATURE [°C] Fig.16 I_{DD} – Ambient temperature

80 100

10.0

8.0

6.0

4.0

20

0.0

10.0 8.0

6.0

4.0

2.0

0.0

2.0

2.4

2.8

SUPPLY VOLTAGE [V]

Fig.17 I_{DD} – Supply voltage

3.2

3.6

BU52012NVX (VDD=1.65~3.6V type)

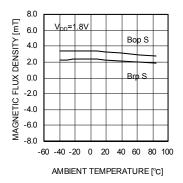


Fig.18 Bop,Brp – Ambient temperature

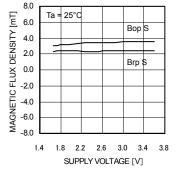


Fig.19 Bop,Brp – Supply voltage

-60 -40 -20 0 20 40 60 80 100

AMBIENT TEMPERATURE [°C]

Fig.22 I_{DD} – Ambient temperature

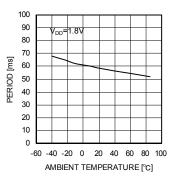


Fig.20 T_P – Ambient temperature

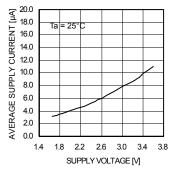
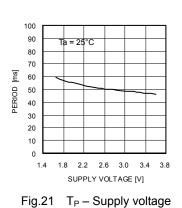


Fig.23 I_{DD} – Supply voltage



BU52012HFV (VDD=1.65~3.3V type)

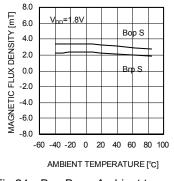
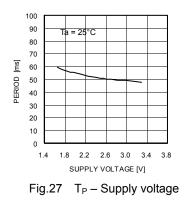


Fig.24 Bop,Brp – Ambient temperature



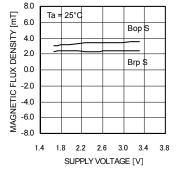
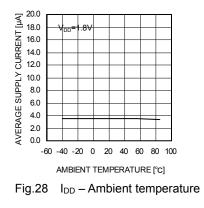


Fig.25 Bop,Brp – Supply voltage



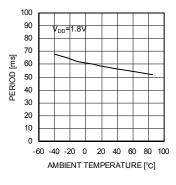
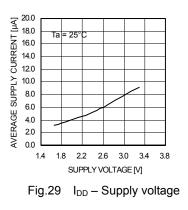
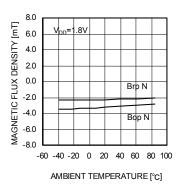


Fig.26 T_P – Ambient temperature



BU52013HFV (VDD=1.65~3.3V type)





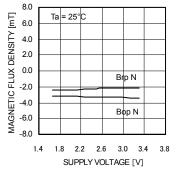


Fig.31 Bop,Brp – Supply voltage

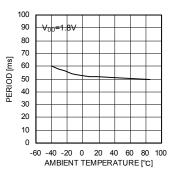
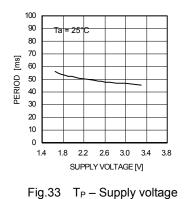


Fig.32 T_P – Ambient temperature



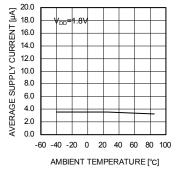


Fig.34 I_{DD} – Ambient temperature

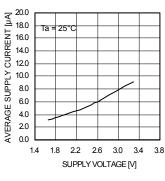
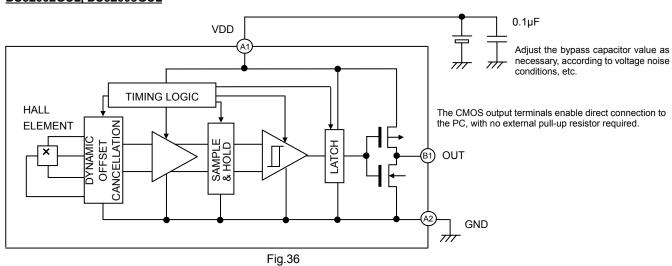


Fig.35 I_{DD} – Supply voltage

Technical Note

Block Diagram BU52002GUL, BU52003GUL

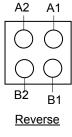


PIN No.	PIN NAME	FUNCTION	COMMENT
A1	VDD	POWER SUPPLY	
A2	GND	GROUND	
B1	OUT	OUTPUT	
B2	N.C.		OPEN or Short to GND.

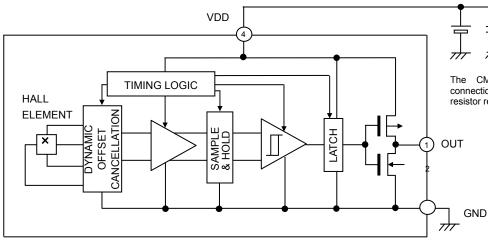
A1	A2
B1 <u>Sur</u>	B2 face

0.1µF

3



BU52012NVX

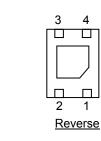


Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc. 777

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

Fig.37

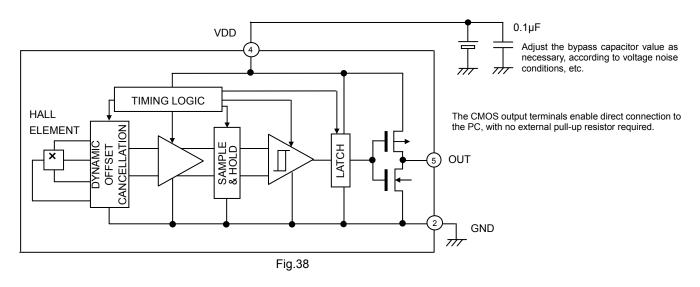
				4 3
PIN No.	PIN NAME	FUNCTION	COMMENT	
1	OUT	OUTPUT		
2	GND	GROUND		
3	N.C.		OPEN or Short to GND.	
4	VDD	POWER SUPPLY		1 2
				Surface



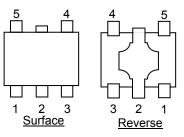
4

1

BU52012HFV, BU52013HFV



PIN No.	PIN NAME	FUNCTION	COMMENT
1	N.C.		OPEN or Short to GND.
2	GND	GROUND	
3	N.C.		OPEN or Short to GND.
4	VDD	POWER SUPPLY	
5	OUT	OUTPUT	



Description of Operations

(Micropower Operation)

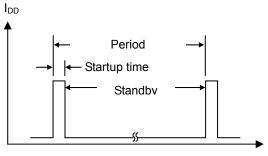
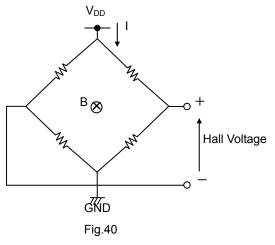


Fig.39

(Offset Cancelation)



The unipolar detection Hall IC adopts an intermittent operation method to save energy. At startup, the Hall elements, amp, comparator and other detection circuit power ON and magnetic detection begins. During standby, the detection circuits power OFF, thereby reducing current consumption. The detection results are held while standby is active, and then output.

Reference period: 50ms (MAX100ms) Reference startup time: 24µs

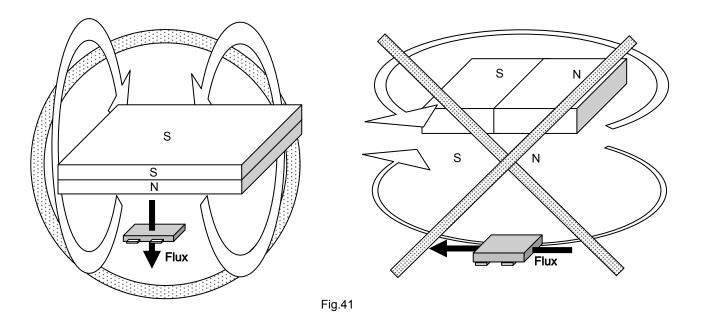
The Hall elements form an equivalent Wheatstone (resistor) bridge circuit. Offset voltage may be generated by a differential in this bridge resistance, or can arise from changes in resistance due to package or bonding stress. A dynamic offset cancellation circuit is employed to cancel this offset voltage.

When Hall elements are connected as shown in Fig. 40 and a magnetic field is applied perpendicular to the Hall elements, voltage is generated at the mid-point terminal of the bridge. This is known as Hall voltage.

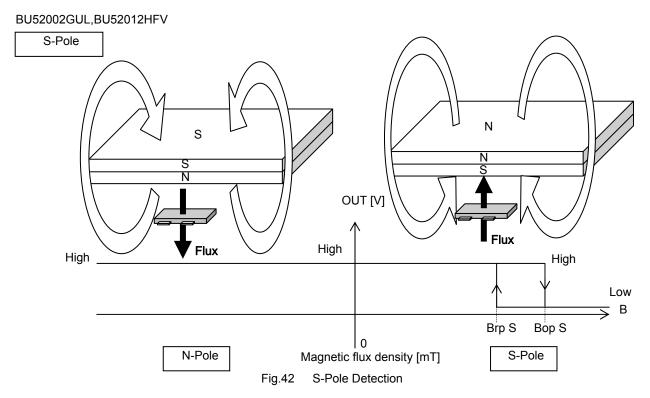
Dynamic cancellation switches the wiring (shown in the figure) to redirect the current flow to a 90° angle from its original path, and thereby cancels the Hall voltage.

The magnetic signal (only) is maintained in the sample/hold circuit during the offset cancellation process and then released.

(Magnetic Field Detection Mechanism)



The Hall IC cannot detect magnetic fields that run horizontal to the package top layer. Be certain to configure the Hall IC so that the magnetic field is perpendicular to the top layer.



BU52002GUL, BU52012HFV detects and outputs for the S-pole only. Since it is unipolar, it does not recognize the N-pole. BU52003GUL, BU52013HFV

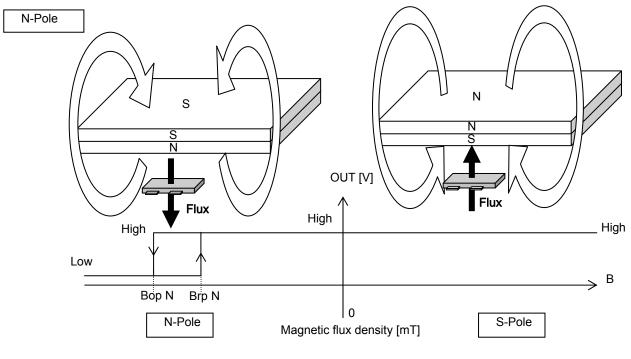
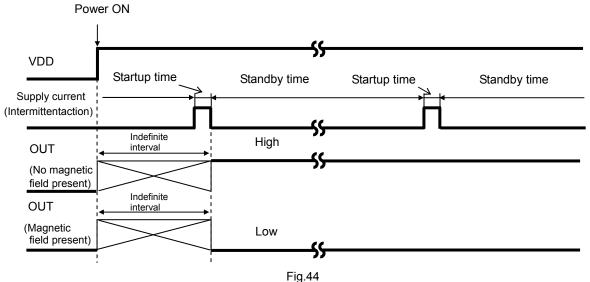


Fig.43 N-Pole Detection

BU52003GUL, BU52013HFV detects and outputs for the N-pole only. Since it is unipolar, it does not recognize the S-pole.

The unipolar detection Hall IC detects magnetic fields running perpendicular to the top surface of the package. There is an inverse relationship between magnetic flux density and the distance separating the magnet and the Hall IC: when distance increases magnetic density falls. When it drops below the operate point (Bop), output goes HIGH. When the magnet gets closer to the IC and magnetic density rises, to the operate point, the output switches LOW. In LOW output mode, the distance from the magnet to the IC increases again until the magnetic density falls to a point just below Bop, and output returns HIGH. (This point, where magnetic flux density restores HIGH output, is known as the release point, Brp.) This detection and adjustment mechanism is designed to prevent noise, oscillation and other erratic system operation.

Intermittent Operation at Power ON



The unipolar detection Hall IC adopts an intermittent operation method in detecting the magnetic field during startup, as shown in Fig.44. It outputs to the appropriate terminal based on the detection result and maintains the output condition during the standby period. The time from power ON until the end of the initial startup period is an indefinite interval, but it cannot exceed the maximum period, 100ms. To accommodate the system design, the Hall IC output read should be programmed within 100ms of power ON, but after the time allowed for the period ambient temperature and supply voltage.

Magnet Selection

Of the two representative varieties of permanent magnet, neodymium generally offers greater magnetic power per volume than ferrite, thereby enabling the highest degree of miniaturization, thus, neodymium is best suited for small equipment applications. Fig.45 shows the relation between the size (volume) of a neodymium magnet and magnetic flux density. The graph plots the correlation between the distance (L) from three versions of a 4mm X 4mm cross-section neodymium magnet (1mm, 2mm, and 3mm thick) and magnetic flux density. Fig.46 shows Hall IC detection distance – a good guide for determining the proper size and detection distance of the magnet. Based on the BU52012HFV, BU52013HFV operating point max 5.0 mT, the minimum detection distance for the 1mm, 2mm and 3mm magnets would be 7.6mm, 9.22mm, and 10.4mm, respectively. To increase the magnet's detection distance, either increase its thickness or sectional area.

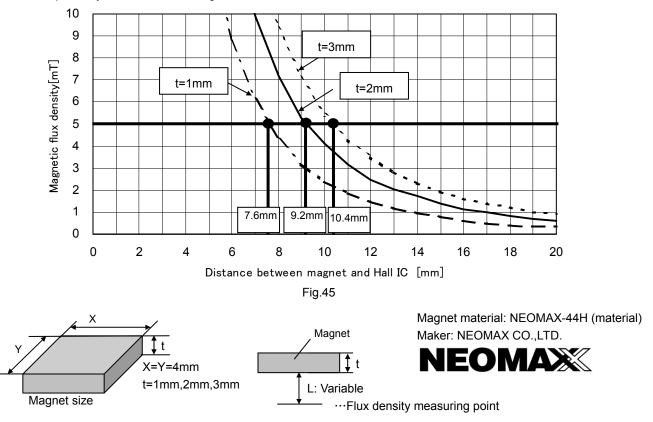
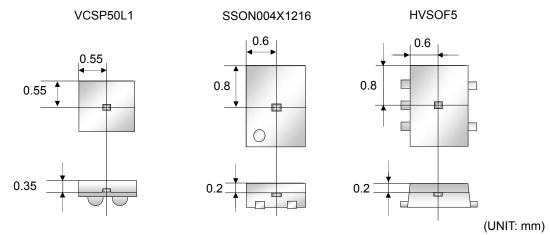
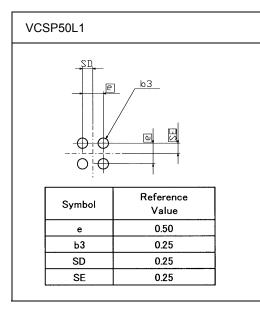


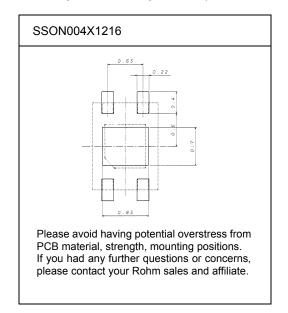
Fig.46 Magnet Dimensions and Flux Density Measuring Point

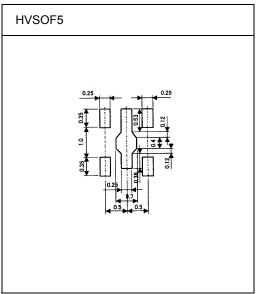
Position of the Hall effect IC(Reference)



•Footprint dimensions (Optimize footprint dimensions to the board design and soldering condition)







(UNIT: mm)

Operation Notes

1) Absolute maximum ratings

Exceeding the absolute maximum ratings for supply voltage, operating conditions, etc. may result in damage to or destruction of the IC. Because the source (short mode or open mode) cannot be identified if the device is damaged in this way, it is important to take physical safety measures such as fusing when implementing any special mode that operates in excess of absolute rating limits.

2) GND voltage

Make sure that the GND terminal potential is maintained at the minimum in any operating state, and is always kept lower than the potential of all other pins.

3) Thermal design

Use a thermal design that allows for sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4) Pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. Mounting errors, such as improper positioning or orientation, may damage or destroy the device. The IC may also be damaged or destroyed if output pins are shorted together, or if shorts occur between the output pin and supply pin or GND.

5) Positioning components in proximity to the Hall IC and magnet Positioning magnetic components in close proximity to the Hall IC or magnet may alter the magnetic field, and therefore the magnetic detection operation. Thus, placing magnetic components near the Hall IC and magnet should be avoided in the design if possible. However, where there is no alternative to employing such a design, be sure to thoroughly test and evaluate performance with the magnetic component(s) in place to verify normal operation before implementing the design.

6) Operation in strong electromagnetic fields Exercise extreme caution about using the device in the presence of a strong electromagnetic field, as such use may cause the IC to malfunction.

7) Common impedance

Make sure that the power supply and GND wiring limits common impedance to the extent possible by, for example, employing short, thick supply and ground lines. Also, take measures to minimize ripple such as using an inductor or capacitor.

8) GND wiring pattern

When both a small-signal GND and high-current GND are provided, single-point grounding at the reference point of the set PCB is recommended, in order to separate the small-signal and high-current patterns, and to ensure that voltage changes due to the wiring resistance and high current do not cause any voltage fluctuation in the small-signal GND. In the same way, care must also be taken to avoid wiring pattern fluctuations in the GND wiring pattern of external components.

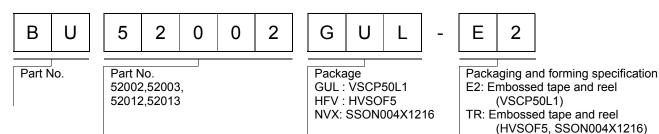
9) Exposure to strong light

Exposure to halogen lamps, UV and other strong light sources may cause the IC to malfunction. If the IC is subject to such exposure, provide a shield or take other measures to protect it from the light. In testing, exposure to white LED and fluorescent light sources was shown to have no significant effect on the IC.

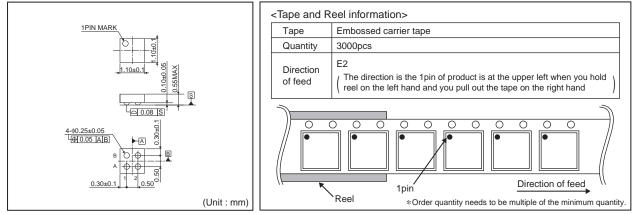
10) Power source design

Since the IC performs intermittent operation, it has peak current when it's ON. Please taking that into account and under examine adequate evaluations when designing the power source.

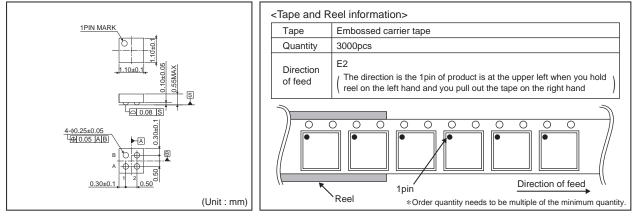
Ordering part number



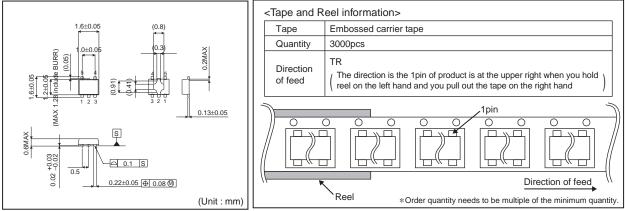
VCSP50L1(BU52002GUL)



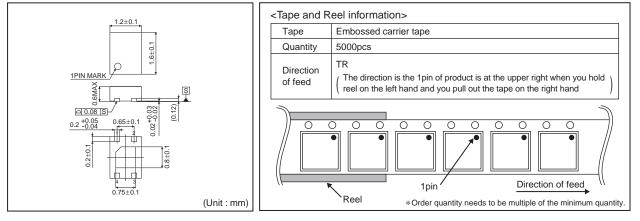
VCSP50L1(BU52003GUL)



HVSOF5



SSON004X1216



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 - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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